

PC123J00000F Series

DIP 4pin Reinforced Insulation Type Photocoupler



■ Description

PC123J00000F Series contains an IRED optically coupled to a phototransistor.

It is packaged in a 4-pin DIP, available in wide-lead spacing option and SMT gullwing lead-form option.

Input-output isolation voltage(rms) is 5.0kV. CTR is 50% to 400% at input current of 5mA.

■ Features

- 1. 4-pin DIP package
- 2. Double transfer mold package (Ideal for Flow Soldering)
- 3. Current transfer ratio (CTR : MIN. 50% at I_F =5 mA, V_{CE} =5V)
- 4. Several CTR ranks available
- 5. Reinforced insulation type (Isolation distance : MIN. 0.4mm)
- 6. Long creepage distance type (wide lead-form type only: MIN. 8mm)
- 7. High isolation voltage between input and output (V_{iso(rms)}: 5.0 kV)
- 8. Lead-free and RoHS directive compliant

■ Agency approvals/Compliance

- Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. PC123)
- Approved by BSI, BS-EN60065, file No. 7087, BS-EN60950 file No. 7409, (as model No. PC123)
- Approved by SEMKO, EN60065, EN60950, (as model No. PC123)
- Approved by DEMKO, EN60065, EN60950 (as model No. PC123)
- 5. Approved by NEMKO, EN60065, EN60950, (as model No. **PC123**)
- Approved by FIMKO, EN60065, EN60950, (as model No. PC123)
- 7. Recognized by CSA file No. CA95323 (as model No. **PC123**)
- 8. Approved by VDE (DIN EN60747-5-2^(*)) (as an option), file No. 40008087 (as model No. **PC123**)
- 9. Package resin: UL flammability grade (94V 0)

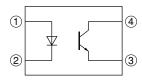
■ Applications

- 1. I/O isolation for MCUs (Micro Controller Units)
- 2. Noise suppression in switching circuits
- 3. Signal transmission between circuits of different potentials and impedances
- 4. Over voltage detection

^(*)DIN EN60747-5-2: successor standard of DIN VDE0884



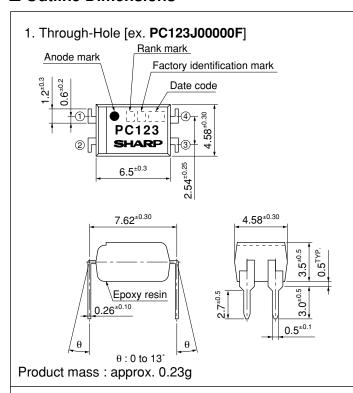
■ Internal Connection Diagram

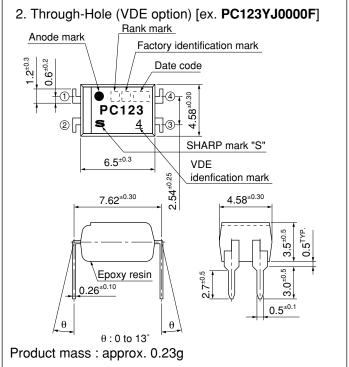


- 1 Anode
- ② Cathode
- 3 Emitter
- 4 Collector

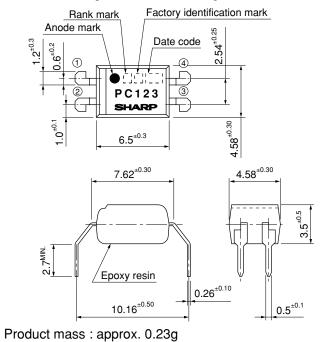
■ Outline Dimensions

(Unit: mm)





3. Wide Through-Hole Lead-Form [ex. PC123FJ0000F]



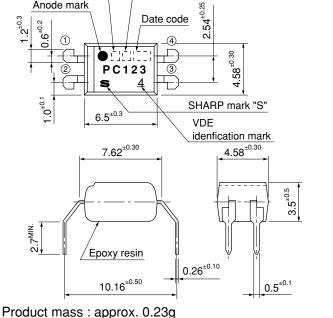
4. Wide Through-Hole Lead-Form (VDE option) [ex. PC123FYJ000F]

Rank mark
Anode mark

Anode mark

Anode mark

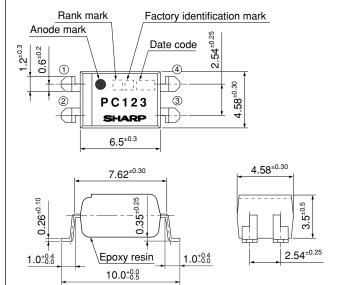
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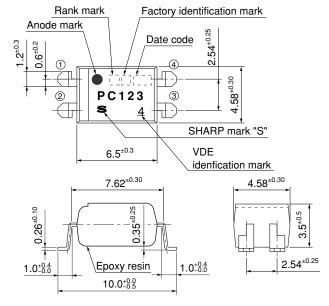
(Unit: mm)

5. SMT Gullwing Lead-Form [ex. PC123PJ0000F]



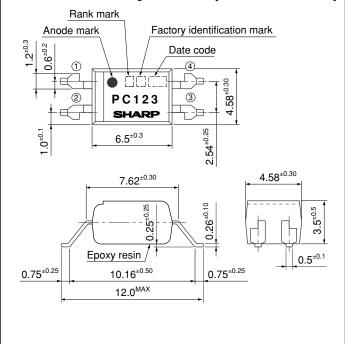
Product mass: approx. 0.22g

6. SMT Gullwing Lead-Form (VDE option) [ex. PC123PYJ000F]

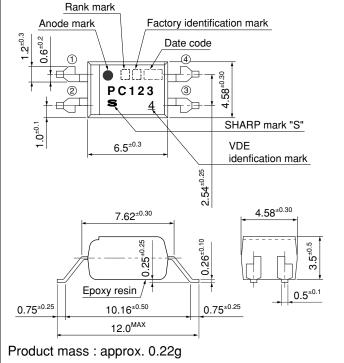


Product mass: approx. 0.22g

7. Wide SMT Gullwing Lead-Form [ex. PC123FPJ000F]



8. Wide SMT Gullwing Lead-Form (VDE option) [ex. PC123ZYJ000F]



Sheet No.: D2-A02904EN

Product mass: approx. 0.22g



Date code (2 digit)

	1st o	digit		2nd digit	
	Year of p	roduction		Month of production	
A.D.	Mark	A.D	Mark	Month	Mark
1990	A	2002	P	January	1
1991	В	2003	R	February	2
1992	С	2004	S	March	3
1993	D	2005	T	April	4
1994	Е	2006	U	May	5
1995	F	2007	V	June	6
1996	Н	2008	W	July	7
1997	J	2009	X	August	8
1998	K	2010	A	September	9
1999	L	2011	В	October	0
2000	M	2012	С	November	N
2001	N	:	:	December	D

repeats in a 20 year cycle

Factory identification mark and Plating material

Factory identification Mark	Country of origin	Plating material	
no mark	Japan	SnCu (Cu : TYP. 2%)	
	Indonesia	SnBi (Bi : TYP. 2%)	
or \	China	SnCu (Cu : TYP. 2%)*	
	Cnina	SnCu (Cu : TYP. 2%)	

* Up to Date code "T4" (April 2005), SnBi (Bi : TYP. 2%).

** This factory making is for identification purpose only.

Please contact the local SHARP sales representative to see the actual status of the production.

Rank mark

Refer to the Model Line-up table



■ Absolute Maximum Ratings

	Absolute Maximum Ratings $(T_a=25^{\circ}C)$						
	Parameter	Symbol	Rating	Unit			
	Forward current	I_F	50	mA			
Input	*1 Peak forward current	I_{FM}	1	A			
Inf	Reverse voltage	V_R	6	V			
	Power dissipation	P	70	mW			
	Collector-emitter voltage	V_{CEO}	70	V			
Output	Emitter-collector voltage	V _{ECO}	6	V			
Out	Collector current	I_{C}	50	mA			
	Collector power dissipation	P_{C}	150	mW			
Total power dissipation		P _{tot}	200	mW			
*2 Isolation voltage		V _{iso (rms)}	5.0	kV			
Operating temperature		T_{opr}	-30 to +100	°C			
Storage temperature		T_{stg}	-55 to +125	°C			
*3 €	Soldering temperature	T_{sol}	260	°C			

^{*1} Pulse width≤100µs, Duty ratio : 0.001 *2 40 to 60%RH, AC for 1 minute, f = 60Hz *3 For 10s

■ Electro-optical Characteristics

 $(T_a=25^{\circ}C)$

	Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
	Forward voltage		$V_{\rm F}$	I _F =20mA	_	1.2	1.4	V
Input	Reverse curre	nt	I_R	$V_R=4V$	_	_	10	μΑ
•	Terminal capacitance		Ct	V=0, f=1kHz	-	30	250	pF
	Collector dark	current	I_{CEO}	$V_{CE} = 50V, I_{F} = 0$	-	-	100	nA
Output	Collector-emitter brea	kdown voltage	BV _{CEO}	$I_{C}=0.1 \text{mA}, I_{F}=0$	70	_	-	V
	Emitter-collector breakdown voltage		BV _{ECO}	$I_{E}=10\mu A, I_{F}=0$	6	_	-	nA
	Collector curr	ent	I_{C}	$I_F=5mA$, $V_{CE}=5V$	2.5	_	20	mA
	Collector-emitter saturation voltage		V _{CE (sat)}	$I_F=20\text{mA}, I_C=1\text{mA}$	_	0.1	0.2	V
Transfer	Isolation resis	tance	R _{ISO}	DC500V, 40 to 60%RH	5×10 ¹⁰	1×10 ¹¹	-	Ω
charac-	charac- Floating capacitance		$C_{\rm f}$	V=0, f=1MHz	-	0.6	1.0	pF
teristics	Cut-off frequency		f_c	V_{CE} =5 V , I_{C} =2 mA , R_{L} =100 Ω , -3 dB	_	80	-	kHz
	Desmanas tima	Rise time	t _r	V 2V I 2m A B 1000	_	4	18	μs
	Response time	Fall time	t_{f}	V_{CE} =2V, I_{C} =2mA, R_{L} =100 Ω	_	3	18	μs

5.0 to 10.0



■ Model Line-up

Lead Form	Through-Hole Wide Through-Hole						
D 1		Rank mark	I _C [mA]				
Package		100pcs/s	sleeve		Kalik Illai k	(I _F =5mA, V _{CE} =5V, T _a =25°C)	
DIN EN60747-5-2		Approved	—— Approved				
	PC123J00000F	PC123YJ0000F	PC123FJ0000F	PC123FYJ000F	with or without	2.5 to 20.0	
	PC123AJ0000F	PC123Y1J000F	PC123F1J000F	PC123FY1J00F	A	2.5 to 7.5	
Model No.	PC123BJ0000F	PC123Y2J000F	PC123F2J000F	PC123FY2J00F	В	5.0 to 12.5	
	PC123CJ0000F	PC123Y5J000F	PC123F5J000F	PC123FY5J00F	No mark	10.0 to 20.0	
	PC123SJ0000F	PC123YSJ000F	PC123FSJ000F	PC123FY8J00F	S	5.0 to 10.0	
Lead Form	SMT Gull	wing	Wide SMT	Gullwing			
D 1		Tapir	ng		Rank mark	I _C [mA]	
Package		2 000pcs	s/reel		Kalik iliai k	$(I_F=5mA, V_{CE}=5V, T_a=25^{\circ}C)$	
DIN EN60747-5-2		Approved		Approved			
	PC123PJ0000F	PC123PYJ000F	PC123FPJ000F	PC123ZYJ000F	with or without	2.5 to 20.0	
	PC123P1J000F	PC123PY1J00F	PC123FP1J00F	PC123ZY1J00F	A	2.5 to 7.5	
Model No.	PC123P2J000F	PC123PY2J00F	PC123FP2J00F	PC123ZY2J00F	В	5.0 to 12.5	
	PC123P5J000F	PC123PY5J00F	PC123FP5J00F	PC123ZY5J00F	No mark	10.0 to 20.0	

PC123FP8J00F

PC123ZY8J00F

Please contact a local SHARP sales representative to inquire about production status.

PC123PSJ000F PC123PY8J00F



Fig.1 Forward Current vs. Ambient Temperature

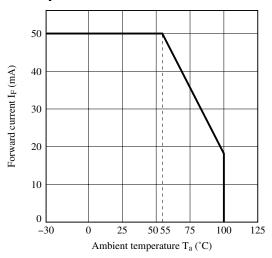


Fig.3 Collector Power Dissipation vs. Ambient Temperature

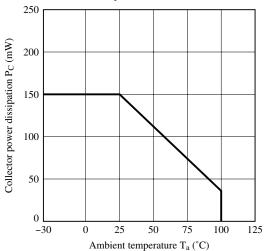


Fig.5 Peak Forward Current vs. Duty Ratio

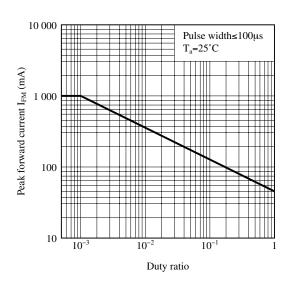


Fig.2 Diode Power Dissipation vs.
Ambient Temperature

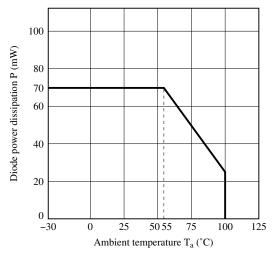


Fig.4 Total Power Dissipation vs. Ambient Temperature

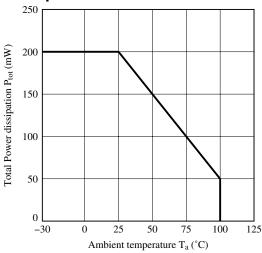


Fig.6 Forward Current vs. Forward Voltage

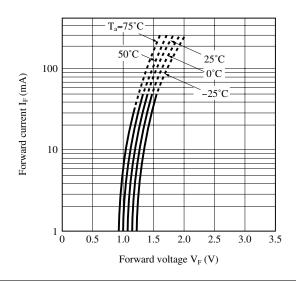




Fig.7 Current Transfer Ratio vs. Forward Current

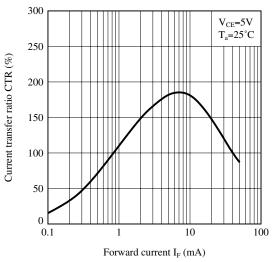


Fig.9 Relative Current Transfer Ratio vs.
Ambient Temperature

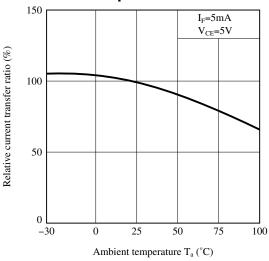


Fig.11 Collector Dark Current vs. Ambient Temperature

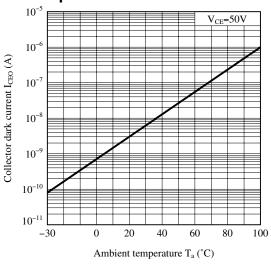


Fig.8 Collector Current vs. Collector-emitter Voltage

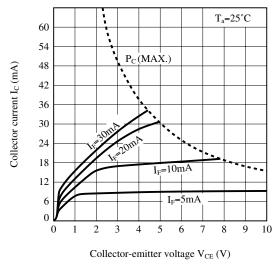


Fig.10 Collector - emitter Saturation Voltage vs. Ambient Temperature

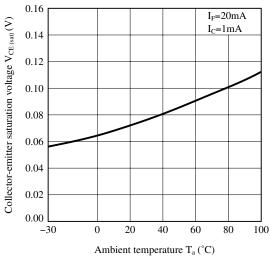


Fig.12 Response Time vs. Load Resistance

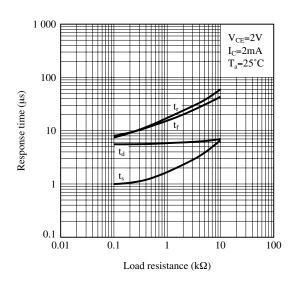




Fig.13 Test Circuit for Response Time

Please refer to the conditions in Fig.12.

Fig.14 Frequency Response

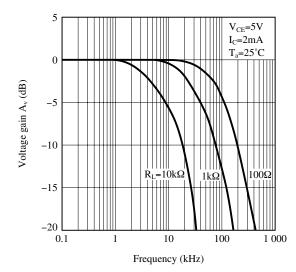
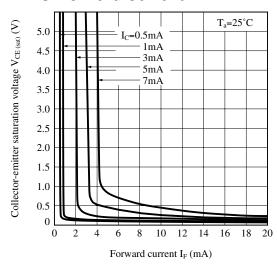


Fig.15 Collector-emitter Saturation Voltage vs. Forward Current



Remarks: Please be aware that all data in the graph are just for reference and not for guarantee.



■ Design Considerations

Design guide

While operating at I_F<1.0mA, CTR variation may increase.

Please make design considering this fact.

This product is not designed against irradiation and incorporates non-coherent IRED.

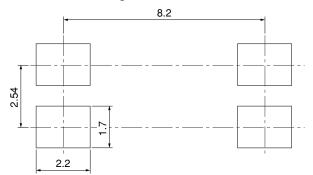
Degradation

In general, the emission of the IRED used in photocouplers will degrade over time.

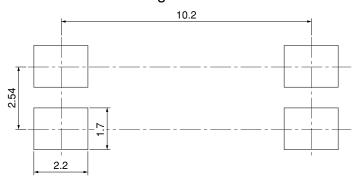
In the case of long term operation, please take the general IRED degradation (50% degradation over 5years) into the design consideration.

Recommended Foot Print (reference)

SMT Gullwing lead-form



Wide SMT Gullwing lead-form



(Unit: mm)

[☆] For additional design assistance, please review our corresponding Optoelectronic Application Notes.



■ Manufacturing Guidelines

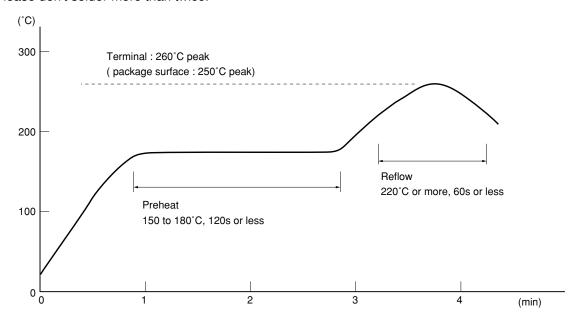
Soldering Method

Reflow Soldering:

Reflow soldering should follow the temperature profile shown below.

Soldering should not exceed the curve of temperature profile and time.

Please don't solder more than twice.



Flow Soldering:

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270°C and within 10s.

Preheating is within the bounds of 100 to 150°C and 30 to 80s.

Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C.

Please don't solder more than twice.

Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.



Cleaning instructions

Solvent cleaning:

Solvent temperature should be 45°C or below Immersion time should be 3minutes or less

Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this product.

Regulation substances: CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBB and PBDE are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive.

•Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).



■ Package specification

Sleeve package

1. Through-Hole

Package materials

Sleeve: HIPS (with anti-static material)

Stopper: Styrene-Elastomer

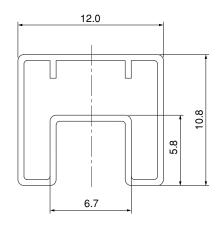
Package method

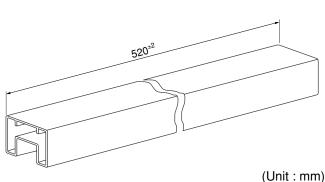
MAX. 100pcs of products shall be packaged in a sleeve. Both ends shall be closed by tabbed and tabless stoppers.

The product shall be arranged in the sleeve with its anode mark on the tabless stopper side.

MAX. 20 sleeves in one case.

Sleeve outline dimensions





2. Wide Through-Hole

Package materials

Sleeve: HIPS (with anti-static material)

Stopper: Styrene-Elastomer

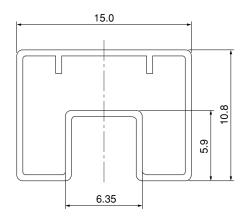
Package method

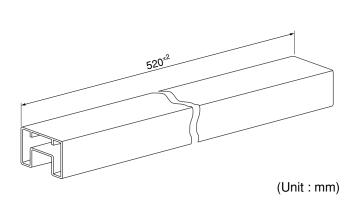
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The product shall be arranged in the sleeve with its anode mark on the tabless stopper side.

MAX. 20 sleeves in one case.

Sleeve outline dimensions







● Tape and Reel package

1. SMT Gullwing

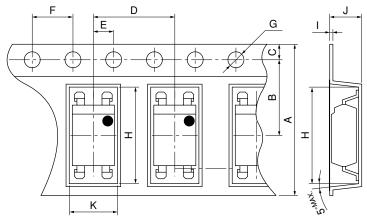
Package materials

Carrier tape: PS

Cover tape: PET (three layer system)

Reel: PS

Carrier tape structure and Dimensions

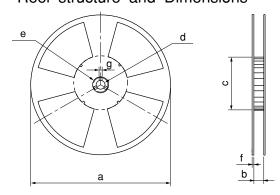


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(Unit: mm)

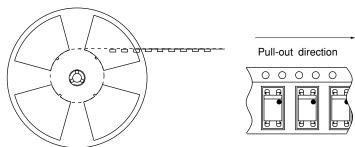
A	В	C	D	Е	F	G
16.0 ^{±0.3}	7.5 ^{±0.1}	1.75 ^{±0.10}	8.0 ^{±0.1}	2.0 ^{±0.1}	4.0 ^{±0.1}	φ1.5 + 8:δ
Н	I	J	K			
10.4 ^{±0.1}	0.40 ^{±0.05}	4.2 ^{±0.1}	5.1 ^{±0.1}			

Reel structure and Dimensions



Dimensio	ns List	(U	nit: mm)
a	b	c	d
ф330	17.5 ^{±1.5}	φ100±1	φ13.0 ^{±0.5}
e	f	g	
φ23 ^{±1}	2.0 ^{±0.5}	2.0 ^{±0.5}	

Direction of product insertion



[Packing: 2 000pcs/reel]



2. Wide SMT Gullwing

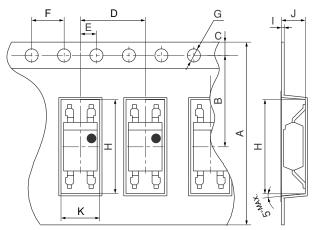
Package materials

Carrier tape : PS

Cover tape: PET (three layer system)

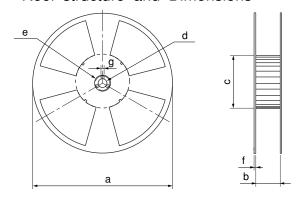
Reel: PS

Carrier tape structure and Dimensions



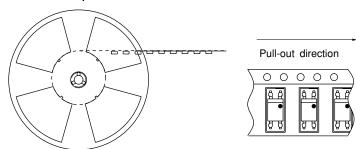
Dimensions List (Unit: mm)						
A	В	С	D	Е	F	G
24.0±0.3	11.5 ^{±0.1}	1.75 ^{±0.10}	8.0 ^{±0.1}	2.0 ^{±0.1}	4.0 ^{±0.1}	φ1.5 ^{+0.1} _{-0.0}
Н	I	J	K			
12.4±0.1	0.40±0.05	4.1±0.1	5.1±0.1			

Reel structure and Dimensions



Dimensio	ns List	(U	nit: mm)
a	b	С	d
ф330	25.5 ^{±1.5}	φ100±1	ф13.0±0.5
e	f	g	
ф23 ^{±1}	2.0 ^{±0.5}	2.0 ^{±0.5}	

Direction of product insertion



[Packing: 2 000pcs/reel]



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 - --- Office automation equipment
 - --- Telecommunication equipment [terminal]
 - --- Test and measurement equipment
 - --- Industrial control
 - --- Audio visual equipment
 - --- Consumer electronics
- (ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection

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- --- Traffic signals
- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.
- (iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:
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